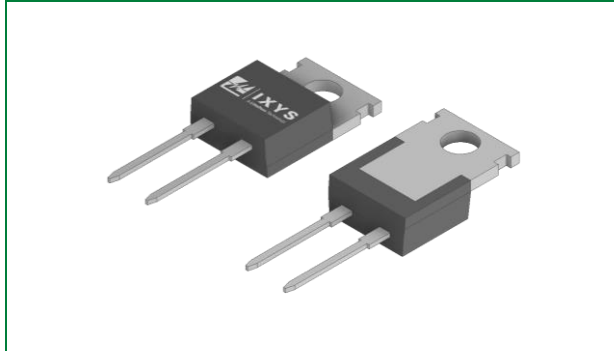


LSIC2SD065A10A 650 V, 10 A SiC Schottky Barrier Diode

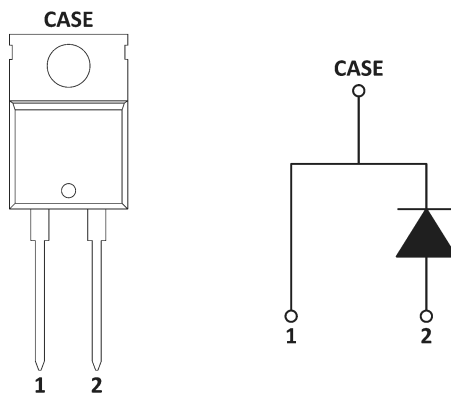


Agency Approvals and Environmental

Environmental Approvals



Circuit Diagram TO-220-2L



Product Summary

Characteristic	Value	Unit
V_{RRM}	650	V
I_F ($T_C = 135\text{ }^\circ\text{C}$)	13	A
Q_C ($V_R: 400\text{ V}$)	31	nC

Description

This series of silicon carbide (SiC) Schottky diodes has negligible reverse recovery current, high surge capability, and a maximum operating junction temperature of $175\text{ }^\circ\text{C}$. These diodes series are ideal for applications where improvements in efficiency, reliability, and thermal management are desired.

Features

- AEC-Q101 qualified
- Positive temperature coefficient for safe operation and ease of paralleling
- $175\text{ }^\circ\text{C}$ maximum operating junction temperature
- Excellent surge capability
- Extremely fast, temperature-independent switching behavior
- Dramatically reduced switching losses compared to Si bipolar diodes
- RoHS compliant, lead-free, and halogen-free

Applications

- Boost diodes in PFC or DC/DC stages
- Switch-mode power supplies
- Solar inverters
- Uninterruptable power supplies
- Industrial motor drives
- Battery Chargers
- High-speed Rectifier

1. Maximum Ratings.....3
2. Thermal Characteristics3
3. Electrical Characteristics ($T_J = 25\text{ }^\circ\text{C}$ unless otherwise specified)3
4. Performance Curves4
5. Diode V_F Model for Simulation5
6. Package Dimensions6
7. Part Numbering and Marking.....7
8. Packing Options7
9. Packing Specifications7

1. Maximum Ratings

Characteristic	Symbol	Conditions	Value	Unit
Repetitive Peak Reverse Voltage	V_{RRM}	-	650	V
DC Blocking Voltage	V_R	$T_J = 25\text{ }^\circ\text{C}$	650	V
Continuous Forward Current	I_F	$T_C = 25\text{ }^\circ\text{C}$	28	A
		$T_C = 135\text{ }^\circ\text{C}$	13	
		$T_C = 148\text{ }^\circ\text{C}$	10	
Non-repetitive Forward Surge Current	I_{FSM}	$T_C = 25\text{ }^\circ\text{C}$, $t_b = 10\text{ ms}$, Half sine pulse	48	A
I^2t	$\int I^2 dt$	$T_C = 25\text{ }^\circ\text{C}$, $t_b = 10\text{ ms}$, Half sine pulse	11.5	A^2s
Power Dissipation	P_{Tot}	$T_C = 25\text{ }^\circ\text{C}$	100	W
		$T_C = 110\text{ }^\circ\text{C}$	43	
Operating Junction Temperature	T_J	-	-55 to 175	$^\circ\text{C}$
Storage Temperature	T_{STG}	-	-55 to 150	$^\circ\text{C}$
Lead Temperature for Soldering	T_{SOLD}	-	260	$^\circ\text{C}$
Mounting Torque	M_D	M3 or 6-32 screw	1.0	Nm
			8.8	In-lb

2. Thermal Characteristics

Characteristic	Symbol	Value	Unit
Maximum Thermal Resistance	$R_{th,Jc,MAX}$	1.5	$^\circ\text{C/W}$

3. Electrical Characteristics ($T_J = 25\text{ }^\circ\text{C}$ unless otherwise specified)

Characteristic	Symbol	Conditions	Value			Unit
			Min	Typ	Max	
Forward Voltage	V_F	$I_F = 10\text{ A}$, $T_J = 25\text{ }^\circ\text{C}$	-	1.5	1.8	V
		$I_F = 10\text{ A}$, $T_J = 175\text{ }^\circ\text{C}$	-	1.8	-	
Reverse Current	I_R	$V_R = 650\text{ V}$, $T_J = 25\text{ }^\circ\text{C}$	-	<1	100	μA
		$V_R = 650\text{ V}$, $T_J = 175\text{ }^\circ\text{C}$	-	20	-	
Capacitance	C	$V_R = 1\text{ V}$, $f = 1\text{ MHz}$	-	470	-	pF
		$V_R = 200\text{ V}$, $f = 1\text{ MHz}$	-	60	-	
		$V_R = 400\text{ V}$, $f = 1\text{ MHz}$	-	43	-	
Total Capacitive Charge	Q_c	$V_R = 400\text{ V}$, $Q_c = \int C(V) dV$	-	31	-	nC
Capacitive Stored Energy	E_c	$V_R = 400\text{ V}$	-	3.4	-	μJ

4. Performance Curves

Figure 1. Typical Forward Characteristics

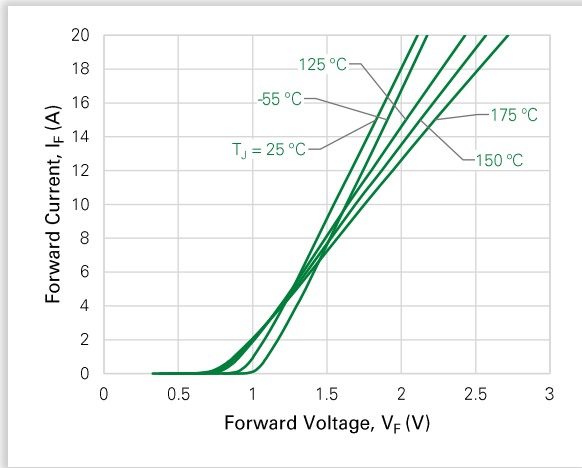


Figure 2. Typical Reverse Characteristics

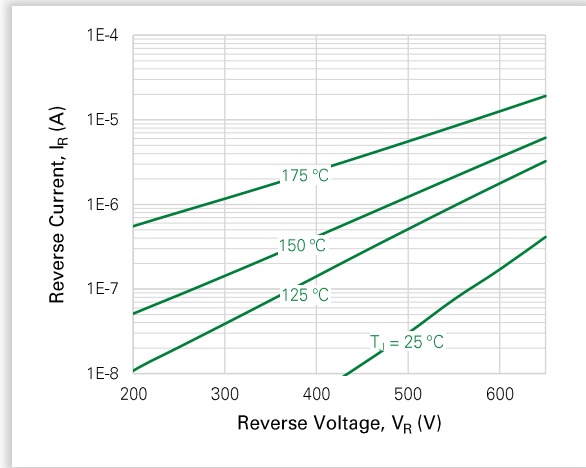


Figure 3. Power Derating

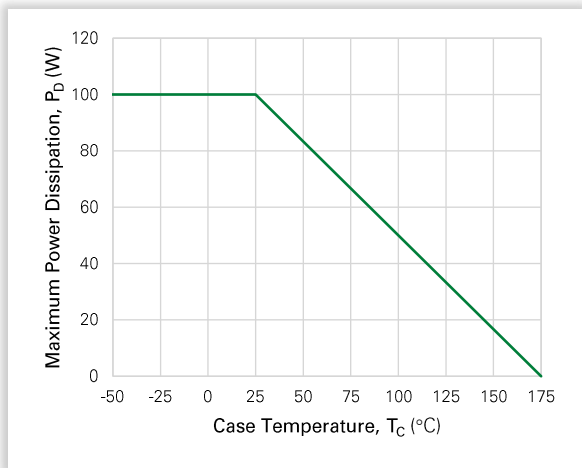


Figure 4. Current Derating

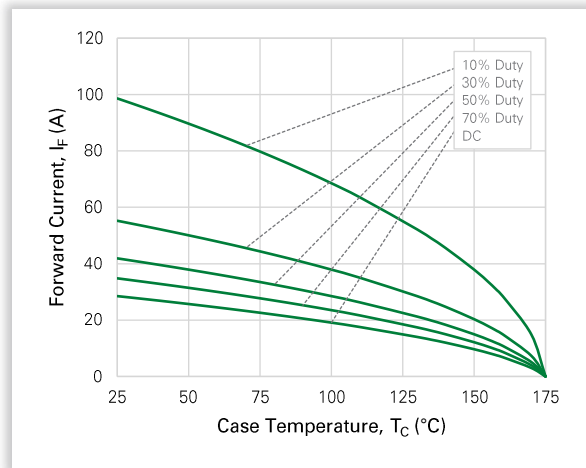


Figure 5. Capacitance vs. Reverse Voltage

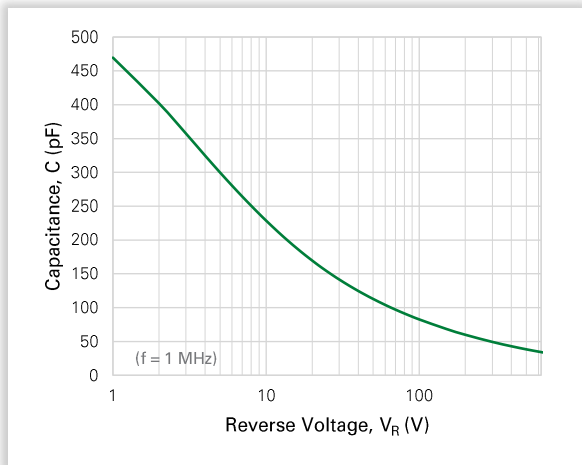


Figure 6. Capacitive Charge vs. Reverse Voltage

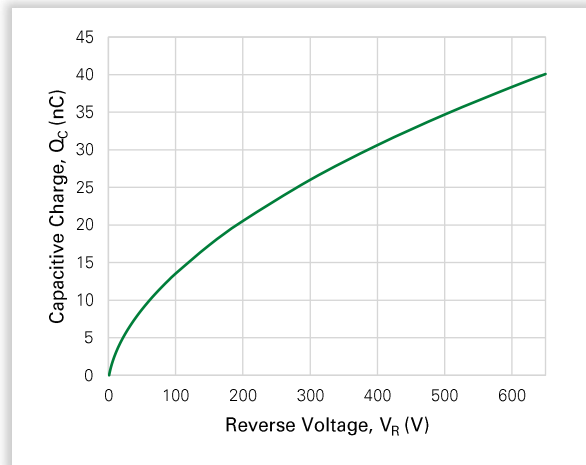


Figure 7. Stored Energy vs. Reverse Voltage

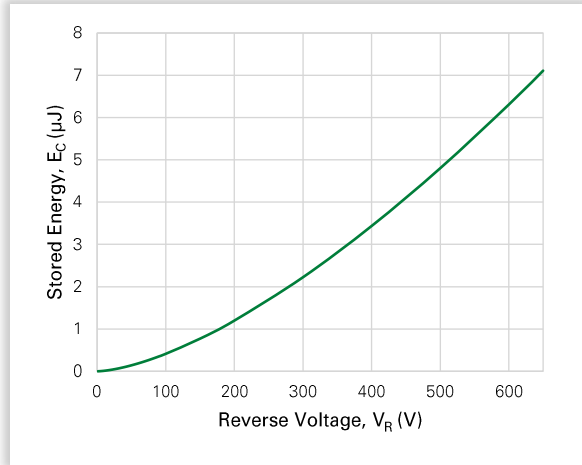
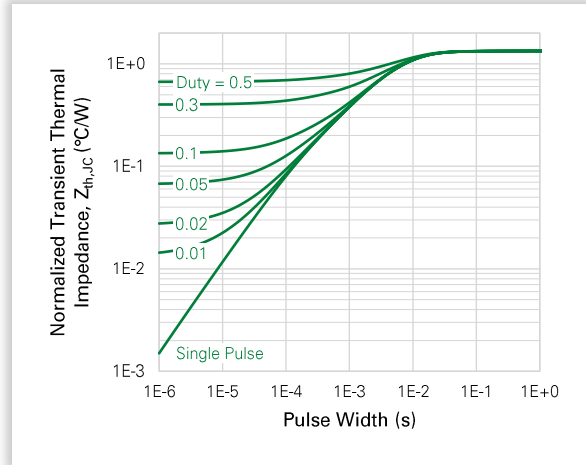
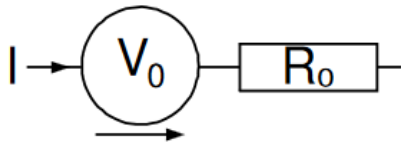


Figure 8. Transient Thermal Impedance



5. Diode V_F Model for Simulation



$$V_F(T_J) = V_0 + IR_0$$

$$V_0 = -1.14 \times 10^{-3} \cdot T_J + 1.01 \times 10^0$$

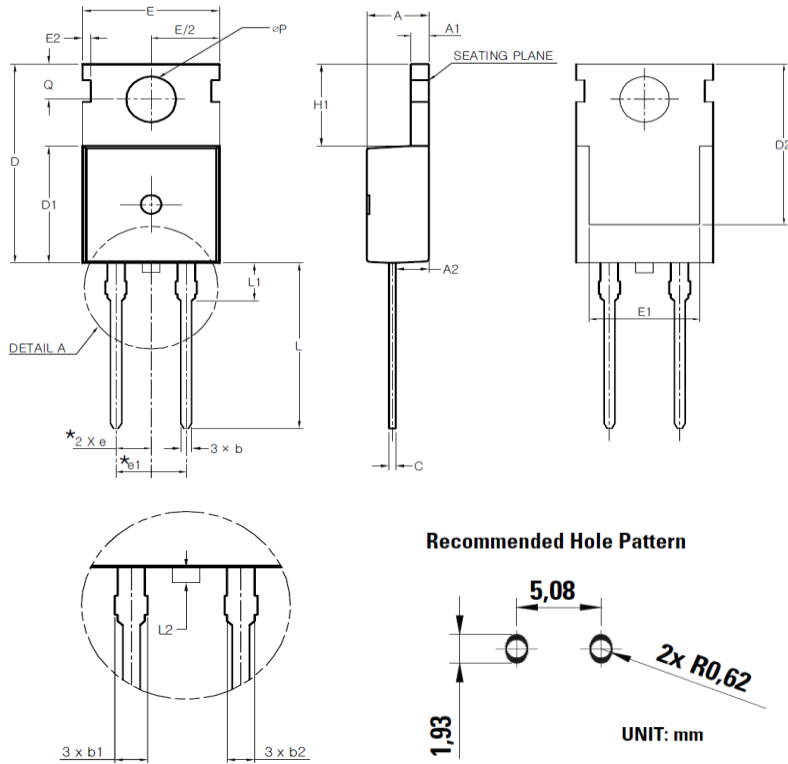
$$R_0 = 8.08 \times 10^{-7} \cdot T_J^2 + 9.46 \times 10^{-5} \cdot T_J + 5.34 \times 10^{-2}$$

Notes:

- T_J is junction temperature in °C
- Range valid from 25 °C to 175 °C
- Model represents performance of a typical part

6. Package Dimensions

TO-220-2L Package

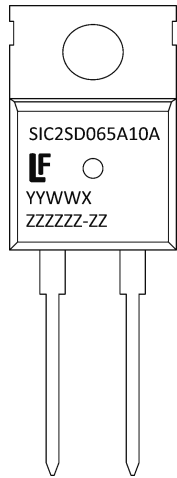


Symbol	Millimeters		
	Min	Nom	Max
A	4.30	4.50	4.70
A1	1.25	1.30	1.40
A2	2.20	2.40	2.60
b	0.70	0.80	0.90
b2	1.17	1.27	1.37
c	0.45	0.50	0.60
D	15.50	15.70	15.90
D1	9.00	9.20	9.40
D2	(12.70)		
E*	9.70	9.90	10.10
E1	(8.00)		
E2	(0.60)		
E3	9.70	9.90	10.10
e	2.54 BSC		
e1	5.08 BSC		
H1	6.30	6.50	6.70
L	12.88	13.08	13.28
L1	(3.00)		
L2	-	-	0.80
øP	3.50	3.60	3.70
Q	2.70	2.80	2.90

Notes:

1. These dimensions do not include protrusions of the mold.
2. The “()” mark is the reference.
3. The “L2” symbol is a protrusion of the mold.

7. Part Numbering and Marking



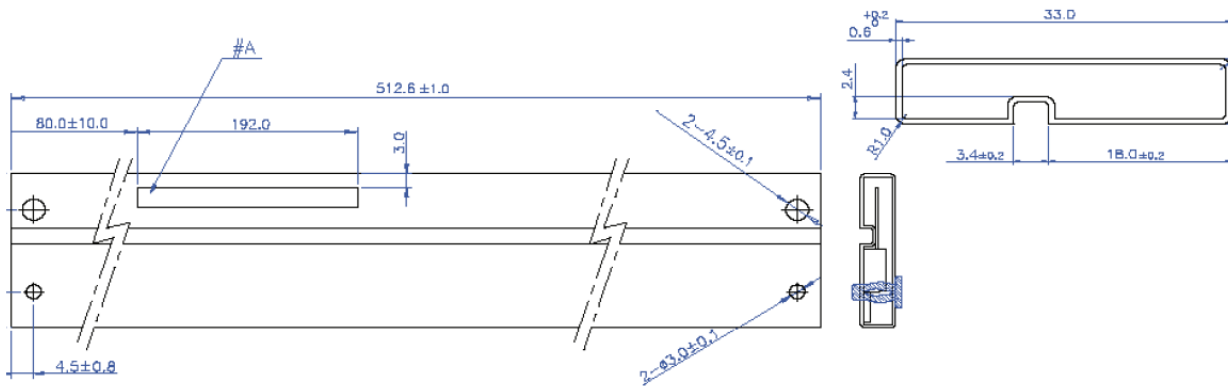
- Sic = SiC Diode
- 2 = Gen2
- SD = Schottky Diode
- 065 = Voltage Rating (650 V)
- A = TO-220 Package (2 Lead)
- 10 = Current Rating (10 A)
- A = AEC-Q101 Qualified
- YY = Year
- VVV = Week
- X = Special Code
- ZZZZZZ-ZZ = Lot Number

8. Packing Options

Part Number	Marking	Packing Mode	M.O.Q.
LSIC2SD065A10A	SIC2SD065A10A	Tube (50 pcs)	1000

9. Packing Specifications

Tube for TO-220-2L



NOTE]

- TUBE
 - MATERIAL : PVC / PET (WITH ANTISTATIC COATING)
 - COLOR : TRANSPARENCY, RED, YELLO
 - MARKING #A : BLACK COLOR, LETTER STYLE : Arial
 - Tube Surface Resistance : $10^9 \sim 10^{11} \Omega$ /square
 - ESD (Electro Static Discharge) : less than 100 [volts], 6 Months
 - CAMBAR : 1.5 MAX
- PIN
 - COLOR : GREEN (ONE PIN MUST BE INSERTED IN LEFT-SIDE OF "□ANTISTATIC~" AND ANOTHER PIN IS FREE.)

For additional information please visit www.Littelfuse.com/powersemi

Disclaimer Notice - Littelfuse products are not designed for, and shall not be used for, any purpose (including, without limitation, automotive, military, aerospace, medical, life-saving, life-sustaining or nuclear facility applications, devices intended for surgical implant into the body, or any other application in which the failure or lack of desired operation of the product may result in personal injury, death, or property damage) other than those expressly forth in applicable Littelfuse product documentation. Littelfuse shall not be liable for any claims or damages arising out of products used in applications not expressly intended by Littelfuse as set forth in applicable Littelfuse documentation.

Read complete Disclaimer Notice at www.littelfuse.com/disclaimer-electronics